PD-2.318 rev. A 12/97

International
IOR Rectifier

MBR1535CT
MBR1545CT

SCHOTTKY RECTIFIER — 15 Amp

Major Ratings and Characteristics

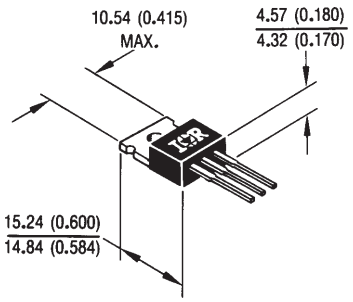
Characteristics	MBR15..CT	Units
$I_{F(AV)}$ Rectangular waveform	15	A
V_{RRM}	35/45	V
I_{FSM} @ tp = 5 µs sine	690	A
V_F @ 7.5 Apk, T_J = 125°C	0.57	V
T_J	-65 to 150	°C

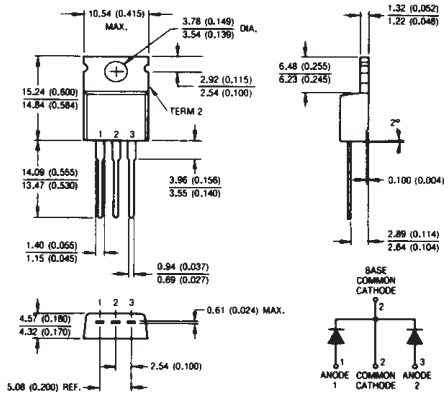
Description/Features

The MBR15..CT center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 150° C T_J operation
- Center tap TO-220 package
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

CASE STYLE AND DIMENSIONS





Conforms to JEDEC Outline TO-220AB
Dimensions in millimeters and inches

Voltage Ratings

	Part number	MBR1535CT	MBR1545CT
V_R	Max. DC Reverse Voltage (V)	35	45
V_{RWM}	Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

	Parameters	MBR15..CT	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current (Per Leg)	7.5	A	@ T_C = 105 °C, (Rated V_R)	
	(Per Device)	15			
I_{FSM}	Max. Peak One Cycle Non Repetitive Surge	690	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
		150		Surge applied at rated load condition halfwave single phase 60Hz	
I_{RRM}	Peak Repetitive Reverse Surge Current	1.0	A	2.0 µsec 1.0 KHz	

Electrical Specifications

	Parameters	MBR15..CT	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop (1)	0.84	V	@ 15A	T_J = 25 °C
		0.57	V	@ 7.5A	T_J = 125 °C
		0.72	V	@ 15A	
I_{RM}	Max. Instantaneus Reverse Current (1)	0.1	mA	T_J = 25 °C	Rated DC voltage
		15	mA	T_J = 125 °C	
C_T	Max. Junction Capacitance	400	pF	V_R = 5V_{DC}, (test signal range 100Khz to 1Mhz) 25°C	
L_S	Typical Series Inductance	8.0	nH	Measured from top of terminal to mounting plane	
dv/dt	Max. Voltage Rate of Change (Rated V_R)	1000	V/ µs		

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

	Parameters		MBR15..CT	Units	Conditions
T_J	Max. Junction Temperature Range		-65 to 150	°C	
T_{stg}	Max. Storage Temperature Range		-65 to 175	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case		3.0	°C/W	DC operation
R_{thCS}	Typical Thermal Resistance, Case to Heatsink		0.50	°C/W	Mounting surface, smooth and greased
R_{thJA}	Max. Thermal Resistance Junction		60	°C/W	DC operation
wt	Approximate Weight		2 (0.07)	g (oz.)	
T	Mounting Torque	Min.	6 (5)	Kg-cm (lbf-in)	
		Max.	12 (10)		
	Case Style		TO-220AB		JEDEC

* For Additional Informations and Graphs, Please See the 12CTQ Series